NSN 5961-01-063-4550

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-063-4550 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Overall Diameter:** 0.155 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 reverse voltage, peak **Current Rating Per Characteristic:** 2.00 microamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Cathode end colored band or dot; terminal lug and sleeving on each wire lead **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0